

# Quantum simulator for the Ising model with electrons floating on a helium film

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We propose a physical setup that can be used to simulate the quantum dynamics of the Ising model with present-day technology. Our scheme consists of electrons floating on superfluid helium which interact via Coulomb forces. In the limit of low temperatures, the system will stay near the ground state where its Hamiltonian is equivalent to the Ising model and thus shows phenomena such as quantum criticality. Furthermore, the proposed design could be generalized in order to study interacting field theories (e.g.,  $\lambda\phi^4$ ) and adiabatic quantum computers.

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*Introduction* Richard Feynman's observation [1] that classical computers cannot effectively simulate quantum systems bred widespread interest in quantum computation. He thought up the idea of a quantum computer which uses the effects of quantum theory instead of classical physics. As an example, Feynman proposed a *universal quantum simulator* consisting of a lattice of spins with nearest neighbor interactions that are freely specifiable and can efficiently reproduce the dynamics of *any* other many-particle quantum system with a finite-dimensional state space [1]. Although such universal quantum computers of sufficient size (e.g., number of QuBits, i.e., spins) are not available yet, it is possible to design a special quantum system in the laboratory which simulates the quantum dynamics of a particular model of interest. Such a designed quantum system can then be regarded as a special quantum computer (instead of a universal one) which just performs the desired quantum simulation, see, e.g., [2, 3, 4].

In the following, we present a design for a quantum simulator for the Ising spin chain in a transverse field and demonstrate that it could be feasible with present-day technology, i.e., electrons floating on a thin superfluid Helium film. A similar idea based on trapped ions has been pursued in [2]. Nevertheless, it is still worthwhile to study an alternative set-up, as different experimental realizations possess distinct advantages and drawbacks. For example, the number of coherently controlled ions in a trap is rather limited at present, whereas our proposal can be scaled up to a large number of electrons more easily.

*The model* We want to simulate the quantum dynamics of the one-dimensional Ising chain consisting of  $n$  spins with nearest-neighbor interaction  $J$  plus a transverse field  $\Gamma$  along the  $x$ -direction ( $\hbar = 1$ )

$$H = - \sum_{j=1}^n \{ \Gamma \sigma_j^x + J \sigma_j^z \sigma_{j+1}^z \}, \quad (1)$$

where  $\sigma_j = (\sigma_j^x, \sigma_j^y, \sigma_j^z)$  are the spin-1/2 Pauli matrices acting on the  $j$ th qubit. This model has been employed in the study of quantum phase transitions and percolation theory [5], spin glasses [5, 6], as well as quantum anneal-

ing [7, 8] etc. Although the Hamiltonian (1) is quite simple and can be diagonalized analytically, the Ising model is considered a paradigmatic example [5] for second-order quantum phase transitions and is rich enough to display most of the basic phenomena in quantum critical points. For  $\Gamma \gg J$ , the ground state is paramagnetic  $|\rightarrow\rightarrow\rightarrow\dots\rangle$  with all spins polarized along the  $x$  axis. In the opposite limit  $\Gamma \ll J$ , the nature of the ground state(s) changes qualitatively and there are two degenerate ferromagnetic ground states with all spins pointing either up or down along the  $z$  axis  $|\uparrow\uparrow\uparrow\dots\rangle$  or  $|\downarrow\downarrow\downarrow\dots\rangle$ . The two regimes are separated by a quantum phase transition at the critical point  $\Gamma_{\text{cr}} = J$ , where the excitation gap vanishes (in the thermodynamic limit  $n \uparrow \infty$ ) and the response time diverges. As a result, driving the system through its quantum critical point at a finite transition rate entails interesting non-equilibrium phenomena [9]. Furthermore, the transverse Ising model can also be used to study the order-disorder transitions at zero temperature driven by quantum fluctuations [7]. Finally, two-dimensional generalizations of the Ising model can be mapped onto certain adiabatic quantum algorithms (see, e.g., [10]).

*The analogue* In order to reproduce the quantum dynamics of the 1+1 dimensional Ising model (1), we propose trapping a large number of electrons on a low-temperature helium film of thickness  $h$  (e.g.,  $h = 110$  nm) adsorbed on a silicon substrate [11]. Due to the polarizability  $\varepsilon \approx 1.06$  of the Helium film, the electrons are bound to its surface (i.e., in  $z$ -direction) via their image charges and the large potential barrier (around 1 eV) for penetration into the helium film [12]. Since the binding energy of around 8 K is much larger than the temperature  $T$  (below 1 K) and the width of the electron wave packet in  $z$ -direction (of order 8 nm) is much smaller than all other relevant length scales, the electron motion is approximately two-dimensional ( $x, y$ -plane).

In our scheme, each single electron on top of the helium film is trapped by a pair of golden spheres of radius  $a$  (e.g.,  $a = 10$  nm) and distance  $d$  (e.g.,  $d = 60$  nm) attached to the silicon substrate (i.e., on the bottom of the helium film, cf. Fig. 1). Depending on its position  $x, y$ ,

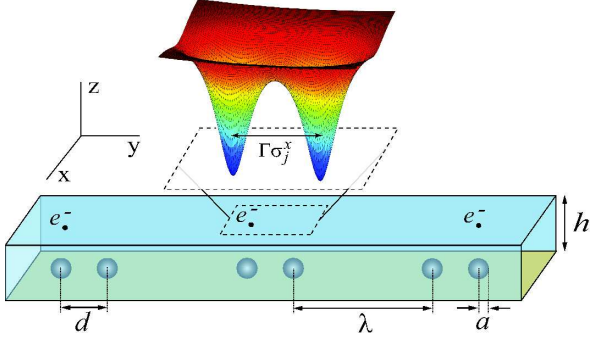


FIG. 1: Sketch of the proposed analogue quantum simulator. Electrons ( $e^-$ ) are floating on a low-temperature helium film of height  $h$  adsorbed on a silicon substrate. A double-well potential for each single electron is created by a pair of golden spheres of radius  $a$  and distance  $d$  on the bottom of the helium film. The double wells at each site provide two lowest states of the electron and model the spin states  $|\uparrow\rangle$  and  $|\downarrow\rangle$  at each site  $j$ . The tunneling rate between the two wells corresponds to the transverse field term  $\Gamma\sigma_j^x$ . The electrons are lined up at distances  $\lambda$  and interact via Coulomb forces, which creates the term  $J\sigma_j^z\sigma_{j+1}^z$ .

the electron will also induce image charges in the two golden spheres (which act as a pair of quantum dots) and hence experience a double-well potential

$$U_w(x, y) = -\frac{ae^2(x^2 + y^2 + \alpha^2 + \beta^2)/4\pi\epsilon}{(x^2 + y^2 + \alpha^2 + \beta^2)^2 - 4\alpha^2y^2}, \quad (2)$$

with  $\alpha = d/2 + a$  and  $\beta^2 = h^2 - a^2$ . Since this potential is symmetric  $U(x, y) = U(x, -y)$ , cf. Fig. 2, the ground state wave-function  $\psi_S(x, y)$  is given by the symmetric superposition of the two Wannier states  $\psi_0(x, \pm y)$  while the first excited state  $\psi_A(x, y)$  is the anti-symmetric combination

$$\begin{aligned} \psi_S(x, y) &= \frac{\psi_0(x, y) + \psi_0(x, -y)}{\sqrt{2}} \rightarrow \frac{|\uparrow\rangle + |\downarrow\rangle}{\sqrt{2}}, \\ \psi_A(x, y) &= \frac{\psi_0(x, y) - \psi_0(x, -y)}{\sqrt{2}} \rightarrow \frac{|\uparrow\rangle - |\downarrow\rangle}{\sqrt{2}}. \end{aligned} \quad (3)$$

For a sufficiently high potential barrier between the two wells, the Wannier state  $\psi_0(x, y)$  is strongly concentrated in the left well and models the spin state  $|\uparrow\rangle$  and vice versa. The tunneling between the two states is then described by the Pauli operator  $\sigma^x$  with  $\sigma^x|\uparrow\rangle = |\downarrow\rangle$  and  $\sigma^x|\downarrow\rangle = |\uparrow\rangle$  such that the tunneling rate  $E_A - E_S$  corresponds to the transverse field  $\Gamma$  in Eq. (1). In the limit of strong localization (e.g., weak tunneling), the energy splitting  $E_A - E_S$  between the two levels can be estimated via the WKB approximation [13]

$$E_A - E_S \approx \frac{\omega}{\pi} \exp\left[-\int_{-y_0}^{y_0} dy |p(y)|\right]. \quad (4)$$

Here  $\omega$  is the oscillation frequency (within one well) and  $\pm y_0$  are the two inner (classical) turning points, cf. Fig. 2.

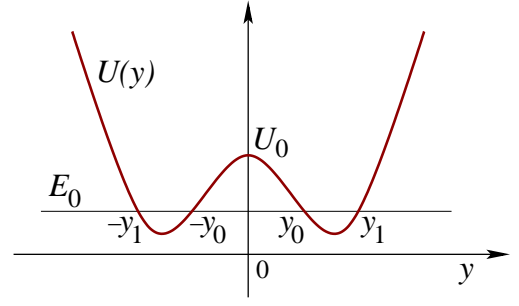


FIG. 2: Sketch of the double-well potential  $U(y)$  with four turning points for the energy  $E_0$ .

The integrand is given by  $p(x, y) = \sqrt{2m_e[E_0 - U(x, y)]}$ , where we can set  $x = 0$  since the tunneling probability away from the  $x = 0$ -axis is strongly suppressed. Finally, the energy  $E_0$  determines the turning points and  $m_e$  is the electron mass. For the parameters above, each valley can well be approximated by a harmonic oscillator

$$U_{w1}(x, y) \approx U_{w1}^x(x) + U_{w1}^y(y) = \frac{ae^2}{4\pi\epsilon\beta^4}(x^2 + y^2), \quad (5)$$

and thus we obtain  $E_0 \approx \sqrt{ae^2/2\pi\epsilon m_e\beta^4} \approx \omega$ .

So far, we derived the term  $\Gamma\sigma_j^x$  in Eq. (1) via Eqs. (2), (3), (4), and (5). In order to simulate the remaining part, we propose to line up the pairs of quantum dots at equal distances  $\lambda$  (e.g.,  $\lambda = 600$  nm), where the parameters are supposed to obey the following hierarchy

$$\lambda \gg h > d \gg a. \quad (6)$$

In this limit, the interaction between the electrons will be dominated by the direct Coulomb repulsion between nearest neighbours  $U_c(x, y) = \sum_{j=1}^n U_c^{j,j+1}$  with  $n$  denoting the number of electrons floating on the helium film. For  $\lambda \gg d$ , we may Taylor expand the Coulomb interaction into powers of  $y/\lambda$  due to  $y \approx \pm d/2$ . The zeroth-order term is constant and thus irrelevant while the first-order contributions vanish (up to boundary terms) after the sum over sites  $j$ . Thus, the leading term is bilinear in the electron positions

$$U_c(x, y) \approx -\frac{e^2}{2\pi\epsilon_0(\lambda + d + 4a)^3} \sum_{j=1}^n y_j y_{j+1}, \quad (7)$$

and precisely corresponds to the  $J\sigma_j^z\sigma_{j+1}^z$  term in Eq. (1) with the effective coupling

$$J = \frac{e^2(d + 2a)^2}{8\pi\epsilon_0(\lambda + d + 4a)^3}. \quad (8)$$

*Experimental parameters* For the example values given in the text, we obtain  $\Gamma \approx 0.1$  K for the tunneling rate and the same value  $J \approx 0.1$  K for the effective coupling, i.e., we are precisely in the quantum critical regime.

However, deviations from this critical point should be easy to realize experimentally by varying the height  $h$  of the helium film, since the tunneling rate depends strongly (in fact, exponentially) on  $h$ , whereas the Coulomb force remains approximately constant. In order to see quantum critical behaviour, i.e., to avoid thermal fluctuations, the temperature should ideally be well below this value 0.1 K (or at least not far above it).

Furthermore, the Coulomb repulsion energy between two electrons (zeroth-order term) of about 11 K would tend to destabilize the electron chain. Fortunately, this effect is compensated by the binding energy between the electron and its image on the sphere, which is around 13 K and thus stabilizes the electron chain. The probability for the electron to penetrate the helium film by tunneling to the sphere is extremely small (of order  $10^{-16}$ ) and can be neglected. Finally, the ground-state energy  $E_0 \approx 1.4$  K (within the harmonic oscillator approximation) is reasonably well below the barrier height  $U_0 \approx 3.1$  K such that the WKB approximation should provide a reasonable estimate. (The tunneling probability 0.08 is also small enough.) On the other hand,  $E_0 \approx 1.4$  K is a measure of the distance between the two lowest-lying states in Eq. (3) and the remaining excited states in the double-well potential. As a result, these additional states do not play a role for temperatures well below one Kelvin and thus the Hamiltonian (1) indeed provides the correct low-temperature description.

*Summary* We have proposed a design for the simulation of the quantum Ising model with a system of electrons floating on a liquid helium film adsorbed on a silicon substrate. Since the energy level splitting (tunneling rate  $\Gamma$ ) depends exponentially on the thickness of the helium film  $h$ , we may tune the system through the quantum phase transition by changing  $h$  – which might even be feasible in a time-dependent manner, cf. [9]. Furthermore, a suitable generalization to two spatial dimensions might be relevant for adiabatic quantum algorithms, see, e.g.,

[10]. Exploring a different limit, where many eigenstates of the double-well potential contribute, the proposed set-up could simulate interacting field theories such as the  $\lambda\phi^4$ -model in 1+1 dimensions.

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